Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	6398	((438/592,684,478,149,488,486, 161) or (257/309,781)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:50
S2	3312	S1 and @pd<"20020315"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:16
S3	935	S2 and ("amorphous silicon" or a-Si)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:17
S4	8	S3 and "silicon nuclei"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:18
S5	718	"solid phase crystallization"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:50
S6	3	S5 and "nuclei-induced"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:52
S7 .	6	"large grain size polysilicon film"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:54
S8	8	(("5893747") or ("6271134") or ("6121120") or ("6190949") or ("6191011") or ("6387779") or ("6391749") or ("5753541")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/09 12:55
S9 .	0	(257/64/66/315/324).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 09:17
S10	4603	(257/64,66,315,324).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 09:18

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S11	1259	S10 and (TFT or (thin adj film adj transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 09:18
S12	124	S11 and (ONO or (floating adj gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 09:18
S13	38	S12 and ((poly adj si) or (polycrystal adj si) or (polycrystalline adj si))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:30
S14	23	S13 and @pd<"20030128"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 09:20
S15	4603	(257/64,66,315,324).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:30
S16	1259	S15 and (TFT or (thin adj film adj transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:30
S17	124	S16 and (ONO or (floating adj gate))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:30
S18	68	S17 and ((poly adj (si or silicon)) or (polycrystal adj (si or silicon)) or (polycrystalline adj (si or silicon)))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:31
S19	37	S18 and @pd<"20030128"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:53
S20	5	S15 and "monolithic three dimensional memory array"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:51

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S21	19	S19 and "memory cells"	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:56
S22	22	S19 and ((3-D or three dimensional) adj memory cells)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:58
S23	0	S19 and ((3-D or "three dimensional") adj "memory array")	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 12:58
S24	8	S19 and ("memory array")	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 13:02
S25	3	(("6525953") or ("6420215") or ("6034882")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 13:14
S26	1	("6960794").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	OFF	2005/11/14 13:14
S27	8	("5229631"   "5548132"   "5693959"   "6093577"   "6413838"   "6420219"   "6646300"   "6677204").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/11/14 13:14

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